

Thyristor Surge Suppressors (TSS) Data Sheet

Description

DO-214AC Thyristor solid state protection thyristor protect telecommunications equipment such as modems, line cards, fax machines, and other CPE.

P Series devices are used to enable equipment to meet various regulatory requirements including GR 1089, ITU K.20, K.21 and K.45, IEC 60950, UL 60950, and TIA-968 (formerly known as FCC Part 68).



Features

Compared to surge suppression using other technologies, P Series devices offer absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). P Series devices:

- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipation typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigue
- Have low capacitance, making them ideal for high-speed transmission equipment
- Meets MSL level 1, per J-STD-020

Electrical Parameters

Parameter	Definition
V_{DRM}	Peak Off-state Voltage – maximum voltage that can be applied while maintaining off state
V_S	Switching Voltage – typical voltage prior to switching to on state
V_T	On-state Voltage – maximum voltage measured at rated on-state current
I_{DRM}	Leakage Current – maximum peak off-state current measured at V_{DRM}
I_S	Switching Current – maximum current required to switch to on state
I_T	On-state Current – maximum rated continuous on-state current
I_H	Holding Current – minimum current required to maintain on state
C_O	Off-state Capacitance – typical capacitance measured in off state
I_{PP}	Peak Pulse Current – maximum rated peak impulse current

Electrical Characteristics


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Part Number	V _{DRM} (V)	V _S (V)	V _T (V)	I _{DRM} (μA)	I _S (mA)	I _T (A)	I _H (mA)	C _O (pF)	I _{PP} 10×1000μs (A)	Marking
P0060CA	5	15	4	5	800	1	10	25	80	6CA

Notes: • All measurements are made at an ambient temperature of 25°C. I_{PP} applies to -40°C through +85°C temperature range.
 • Off-state capacitance(C_O) is measured at 1 MHz with a 2V bias and is typical value.
 • Rating Surge Voltage: 4KV (10/700μs)

Thermal Considerations

Package DO-214AC/SMA	Symbol	Parameter	Value	Unit
	T _J	Operating Junction Temperature	-40 to +125	°C
	T _S	Storage Temperature Range	-40 to +125	°C
	R _{θJA}	Junction to Ambient on printed circuit	90	°C/W

Characteristics Curves

Figure 1. V-I Characteristics

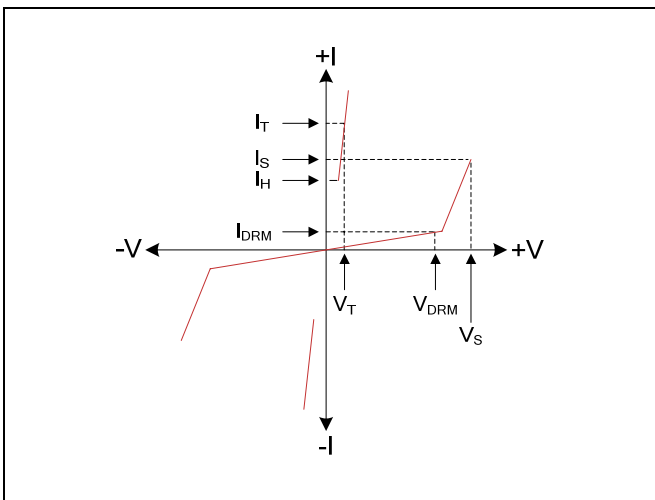


Figure 2. tr × td Pulse Wave-form

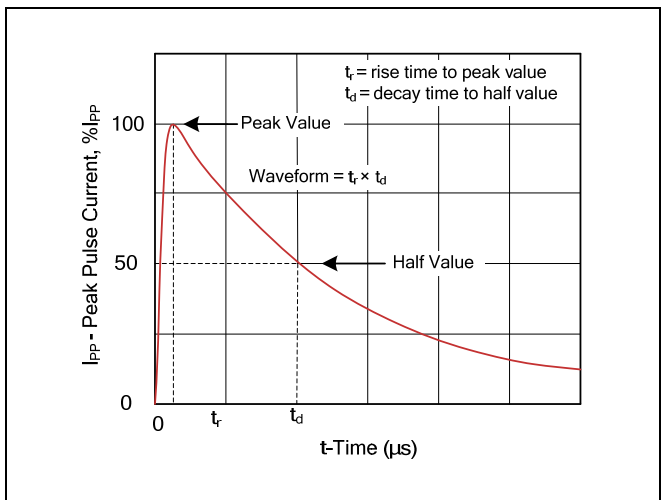


Figure 3. Normalized V_S Change versus Junction Temperature

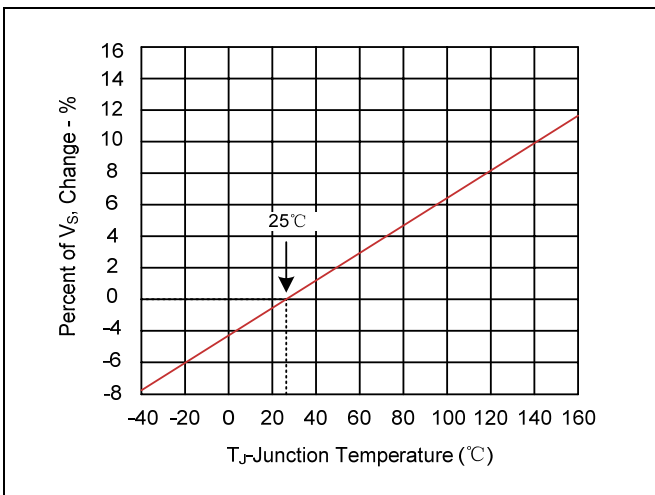
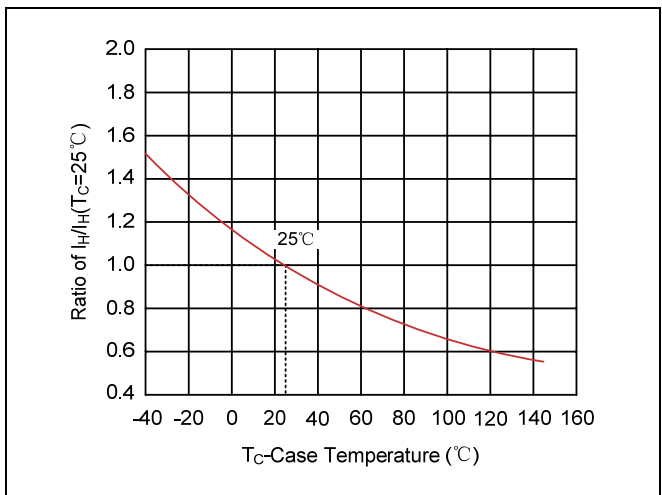
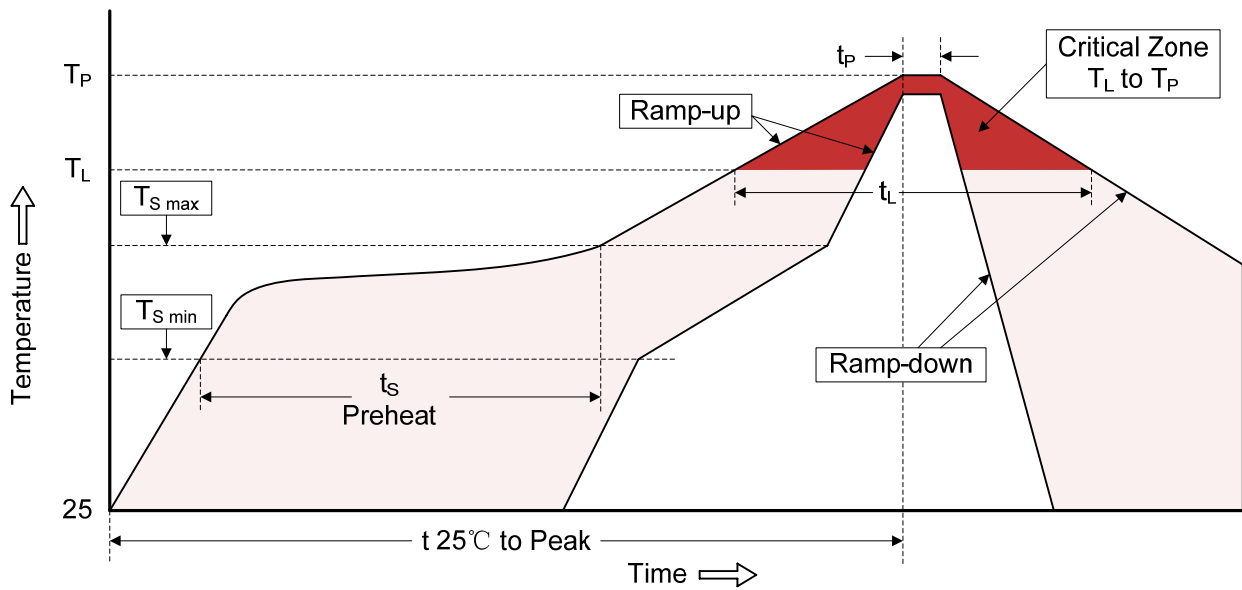


Figure 4. Normalized DC Holding Current versus Case Temperature



Recommended Soldering Conditions

Reflow Soldering



Recommended Conditions

Profile Feature	Pb-Free Assembly
Average ramp-up rate (TL to TP)	3°C/second max.
Preheat -Temperature Min (TSmin) -Temperature Max (TSmax) -Time (min to max) (ts)	150°C 200°C 60-180 seconds
TSmax to TL -Ramp-up Rate	3°C/second max.
Time maintained above: -Temperature (TL) -Time (tL)	217°C 60-150 seconds
Peak Temperature (TP)	260°C
Time within 5°C of actual Peak Temperature (tp)	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

Symbol	Millimeters		Inches	
	Min.	Max.	Min.	Max.
L	3.99	4.50	0.157	0.177
D	2.54	2.79	0.100	0.110
D1	1.25	1.65	0.049	0.065
T	4.93	5.28	0.194	0.208
T1	0.76	1.52	0.030	0.060
d	-	0.203	-	0.008
H	2.00	2.50	0.079	0.098

Packaging

Tape		Symbol	Dimension (mm)
		W	12.00±0.20
		P0	4.00±0.10
		P1	4.00±0.10
		P2	2.00±0.10
		D0	Φ1.50±0.10
		D1	Φ1.50±0.10
		E	1.50±0.10
		F	5.65±0.05
		A0	2.79±0.15
		B0	5.33±0.15
		K0	2.55±0.10
		T	0.25±0.05
		Reel	
		D3	Φ13.5±0.5
		H	2.5±0.5
		W1	16.0±1.0
		Quantity: 5000PCS	

单击下面可查看定价，库存，交付和生命周期等信息

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